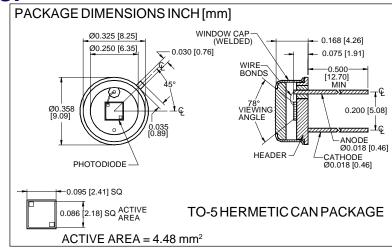
PHOTONIC Silicon Photodiode, Blue Enhanced Photoconductive DETECTORS INC. Type PDB-C105





FEATURES

- High speed
- Low capacitance
- Blue enhanced
- Low dark current

DESCRIPTION

The **PDB-C105** is a silicon, PIN planar diffused, blue enhanced photodiode. Ideal for high speed photoconductive applications. Packaged in a hermetic TO-5 metal can with a flat window.

APPLICATIONS

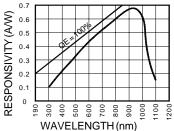
- Instrumentation
- Laser detection
- Medical sensor
- Industrial control

ABSOLUTE MAXIMUM RATING (TA=25°C unless otherwise noted)

SYMBOL	PARAMETER	MIN	MAX	UNITS
V _{BR}	Reverse Voltage		100	V
T _{STG}	Storage Temperature	-55	+150	°C
То	Operating Temperature Range	-40	+125	°C
Ts	Soldering Temperature*		+240	°C
IL	Light Current		0.5	mA

^{*1/16} inch from case for 3 secs max

SPECTRAL RESPONSE



ELECTRO-OPTICAL CHARACTERISTICS (TA=25°C unless otherwise noted)

				/		
SYMBOL	CHARACTERISTIC	TESTCONDITIONS	MIN	TYP	MAX	UNITS
Isc	Short Circuit Current	H = 100 fc, 2850 K	40	56		μ A
ΙD	Dark Current	H = 0, V _R = 10 V		1.0	5.0	nA
Rsн	Shunt Resistance	$H = 0, V_R = 10 \text{ mV}$.5	2.0		GΩ
TC RsH	RSH Temp. Coefficient	$H = 0, V_R = 10 \text{ mV}$		-8		%/℃
Cı	Junction Capacitance	H = 0, V _R = 10 V**		11		pF
λrange	Spectral Application Range	Spot Scan	350		1100	nm
λр	Spectral Response - Peak	Spot Scan		950		nm
VBR	Breakdown Voltage	I = 10 μA	100	125		V
NEP	Noise Equivalent Power	V _R = 10 V @ Peak		2.0x10 ⁻¹⁴		W/ √Hz
tr	Response Time	$RL = 1 K\Omega V_p = 50 V$		12		nS